

Feature

- Precision MEMS process
- •High performance, shielded, Micro-cavity structure
- •Silicon substrate, 50Ω CPW output
- •Au wire bonding, for MCM applications

Environmental Specifications

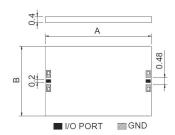
| Operating Temperature | rature -55°C~+85°C | |
|-----------------------|--------------------|--|
| Storage Temperature | -55°℃~+125°℃ | |
| Max. Input Power | 35dBm | |

Electrical Specifications(T_A=+25°C)

| Parameter | Min. | Тур. | Max. | Unit |
|---------------------------------|----------------------|------|------|------|
| Center Freq. (f ₀) | - | 10 | ı | GHz |
| Pass Band | 8 | ı | 12 | GHz |
| Ripple in Pass band | - | ı | 1 | dB |
| Insertion Loss @ f ₀ | - | ı | 2.8 | dB |
| Return Loss | 15 | ı | ı | dB |
| | ≥30@7.07GHz&13.04GHz | | | dB |
| Out of band | ≥40@6.75GHz&13.21GHz | | | dB |
| Attenuation | ≥60@DC-5.41GHz | | | dB |
| | ≥60@13.5-13.9GHz | | | dB |
| Group Delay Variation | ≤0.3@8-12GHz | | | ns |
| Linear Phase | ≤±14@8-12GHz | | | |

S2P file name: SiMS10_4-11D2.s2p

Outline Drawing



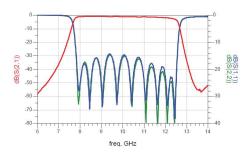
| | Value (mm) | | | |
|--------|------------|---------|------|--|
| Symbol | Min. | Nominal | Max. | |
| Α | 7.9 | - | 8.0 | |
| В | 3.3 | - | 3.4 | |

Typical Test Curves

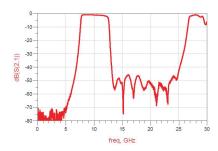
Insertion Loss VS Frequency (T_A=25°C)



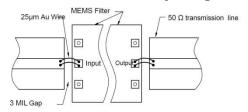
Insertion Loss & Return Loss VS Frequency (T_A=25°C)



Broadband Insertion Loss VS Frequency (T_A=25°C)

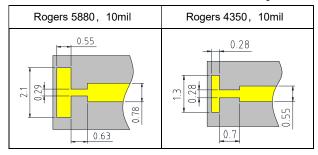


Recommended Assembly Diagrams



Application Notes:

- 1. The chip is back-metalized and can be die mounted with AuSn eutectic performs or with electrically conductive epoxy (for example ME8456).
- 2. The die should be assembled on carriers like Kovar or Mu-Cu which have same Coefficient of thermal expansion. (2.9ppm/ $^{\circ}$ C) with Silicon, thickness 0.2mm max.
- 3. Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.
- 4. Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers.
- 5. Recommended to use T structure as below for bonding.



6. If you have any questions, please contact us.